PH1214-12M

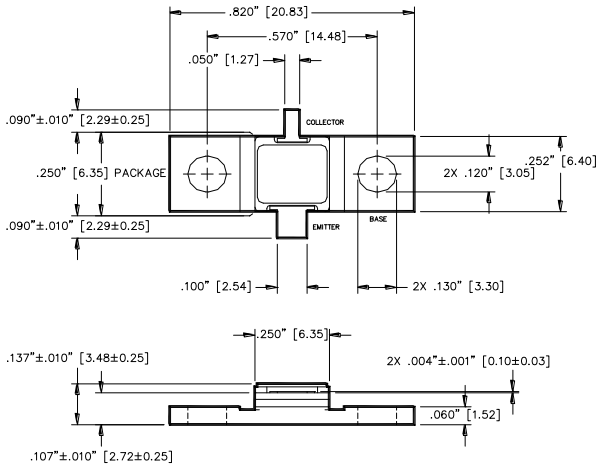
Radar Pulsed Power Transistor
12W, 1.2-1.4 GHz, 150µs Pulse, 10% Duty

Rev. V1

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES ±.005" [MILLIMETERS ±0.13mm]

Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CES}	70	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Collector Current (Peak)	I_C	1.3	A
Power Dissipation @ +25°C	P_{TOT}	47	W
Storage Temperature	T_{STG}	-65 to +200	°C
Junction Temperature	T_J	200	°C

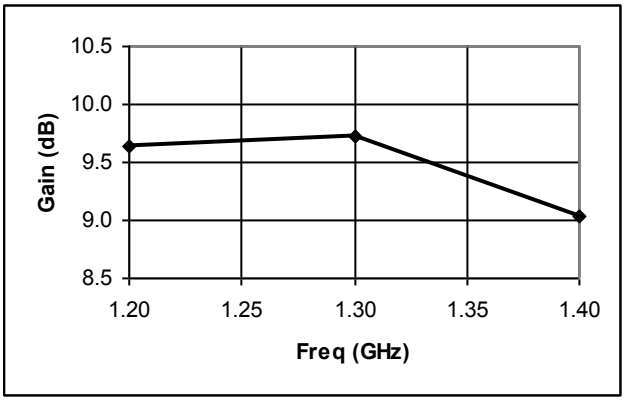
Electrical Specifications: T_C = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I_C = 12.5mA		BV_{CES}	60	-	V
Collector-Emitter Leakage Current	V_{CE} = 40V		I_{CES}	-	1.25	mA
Thermal Resistance	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	$R_{TH(JC)}$	-	3.7	°C/W
Output Power	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	P_{IN}	-	1.7	W
Power Gain	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	G_P	8.5	-	dB
Collector Efficiency	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	η_C	45	-	%
Input Return Loss	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	RL	-	-9	dB
Load Mismatch Tolerance	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 28V, Pout = 12W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

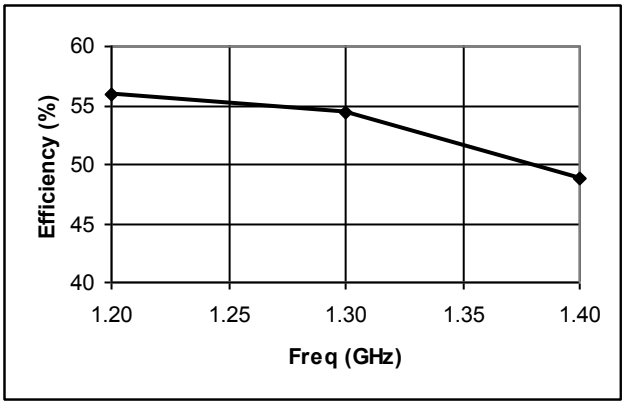
Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	1.31	12.0	9.64	0.77	56.0	-11.9	S	P
1.3	1.28	12.0	9.72	0.79	54.4	-17.4	S	P
1.4	1.49	12.0	9.04	0.88	48.8	-17.2	S	P

Gain vs. Frequency

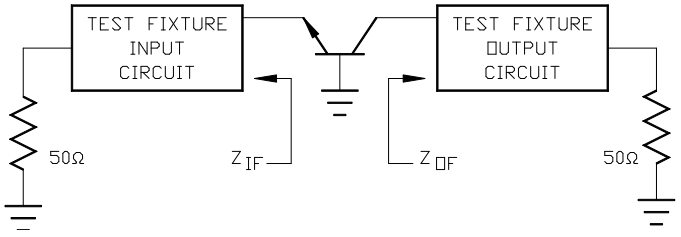


Collector Efficiency vs. Frequency



RF Test Fixture Impedance

F (GHz)	Z_{IF} (Ω)	Z_{OF} (Ω)
1.2	3.7 - j5.3	5.0 + j6.0
1.3	3.5 - j4.4	7.1 + j5.1
1.4	3.4 - j3.8	7.7 + j3.6



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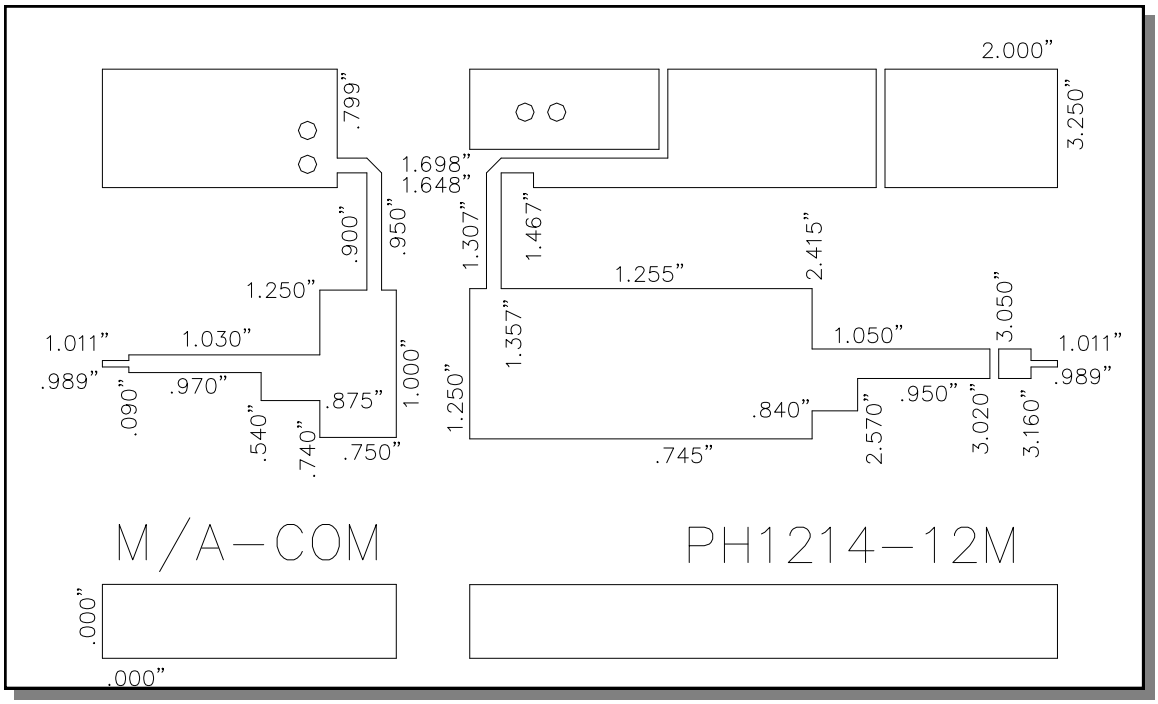
Test Fixture Circuit Dimensions



Test Fixture Assembly